# MOS FET Power Amplifier Module for UHF Band

# **HITACHI**

ADE-208-343C (Z) 3rd. Edition December, 1996

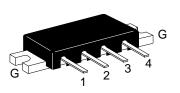
#### **Features**

Small package:30 × 10 × 5.9mm
Low operation voltage: 7W at 7.2V
Low power control current: 200µA Typ

#### **Ordering Infomation**

Type. name	Operating frequency	
PF0348	330 to 360MHz	
PF0349	400 to 430MHz	
PF0350	440 to 470MHz	
PF0351	470 to 490MHz	
PF0352	490 to 520MHz	
PF0353	360 to 380MHz	

#### Pin Arrangement



- 1: Pin
- 2: Vapc
- 3: Vdd
- 4: Pout
- G: GND

### **Absolute Maximum Ratings** ( $Tc = 25^{\circ}C$ )

Item	Symbol	Rating	Unit
Supply voltage	VDD	17	V
Supply current	IDD	3	А
PC voltage	VPC	7	V
Input power	Pin	100	mW
Operating case temperature	Tc (op)	-30 to +100	°C
Storage temperature	Tstg	-40 to +110	°C

### **PF0348 Electrical Characteristics** ( $Tc = 25^{\circ}C$ )

Item	Symbol	Min	Тур	Max	Unit	Test Condition	
Drain cutoff current	IDS	_	_	100	μΑ	VDD = 17V, VPC = 0V, RL = Rg = $50\Omega$	
Total efficiency	ηT	35	38	_	%	Pin = 50mW, VDD = 7.2V,	
2nd harmonic distortion	2nd H.D.	_	-25	-20	dBc	Pout = 6.8W (at Vpc controlled),	
3rd harmonic distortion	3rd H.D.	_	-35	-30	dBc	RL = Rg = $50\Omega$ , Tc = $25^{\circ}$ C	
Input VSWR	VSWR (in)	_	2.0	3.0	_		
Output power (1)	Pout (1)	6.8	7.5	_	W	$\begin{aligned} &\text{Pin} = 50\text{mW},  \text{VDD} = 7.2\text{V}, \\ &\text{VPC} = 6.0\text{V},  \text{RL} = \text{Rg} = 50\Omega \end{aligned}$	
Output power (2)	Pout (2)	4.0	5.0	_	W	$\begin{aligned} \text{Pin} &= 50 \text{mW},  \text{VDD} = 6.0 \text{V}, \\ \text{VPC} &= 5.5 \text{V},  \text{RL} = \text{Rg} = 50 \Omega \end{aligned}$	
Load VSWR tolerance	_	No degradation –			_	Pin = 50mW, VDD = 15V, Pout ≤ 6.8W (at Vpc controlled), Output VSWR = 6 : 1 All phases	
Stability	_	No parasitic oscillation			_	Pin = 50mW, VDD = 6 to 15V, Pout ≤ 6.8W (at Vpc controlled), Output VSWR = 6 : 1 All phases	

### **PF0349/50/51/52/53 Electrical Characteristics** (Tc = 25°C)

Item	Symbol	Min	Тур	Max	Unit	Test Condition
Drain cutoff current	IDS	_	_	100	μΑ	VDD = 17V, VPC = 0V, RL = Rg = $50\Omega$
Total efficiency	ηT	35	38	_	%	Pin = 50mW, VDD = 7.2V,
2nd harmonic distortion	2nd H.D.	_	-30	-25	dBc	Pout = 7W (at Vpc controlled),
3rd harmonic distortion	3rd H.D.	_	-60	-40	dBc	$RL = Rg = 50\Omega$ , $Tc = 25$ °C
Input VSWR	VSWR (in)		2.0	3.0	_	
Output power (1)	Pout (1)	7.0	8.0	_	W	$\begin{aligned} & \text{Pin} = 50 \text{mW},  \text{VDD} = 7.2 \text{V}, \\ & \text{VPC} = 6.0 \text{V},  \text{RL} = \text{Rg} = 50 \Omega \end{aligned}$
Output power (2)	Pout (2)	4.0	5.0	_	W	$\begin{aligned} & \text{Pin} = 50 \text{mW},  \text{VDD} = 6.0 \text{V}, \\ & \text{VPC} = 5.5 \text{V},  \text{RL} = \text{Rg} = 50 \Omega \end{aligned}$
Load VSWR tolerance	_	No degradation —			_	Pin = 50mW, VDD = 15V, Pout ≤ 7W (at Vpc controlled), Output VSWR = 6 : 1 All phases
Stability	_	No parasitic oscillation —			<del>-</del>	Pin = 50mW, VDD = 6 to 15V, Pout ≤ 7W (at Vpc controlled), Output VSWR = 6 : 1 All phases

#### **Package Dimensions**

Unit: mm

